



HFZT

MMSD914

## Small Signal Switching Diodes

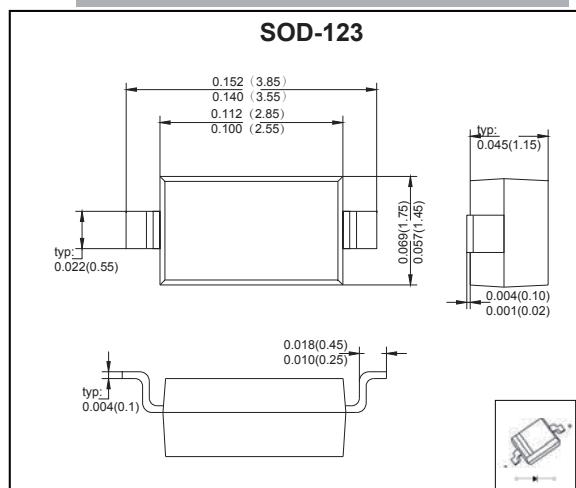
VOLTAGE RANGE: 100V  
PEAK PULSE POWER: 400mW

### FEATURES

- High Voltage

### MECHANICAL DATA

- Case: SOD-123 Small Outline Plastic Packag
- Polarity: Color band denotes cathode end
- Mounting Position: Any



### MAXIMUM RATINGS AND CHARACTERISTICS

@ 25°C Ambient Temperature (unless otherwise noted)

Symbol	Parameter	Value	Unit
$V_{RRM}$	Maximum Repetitive Reverse Voltage	100	V
$I_o$	Forward Current	0.2	A
$I_{FSM}$	Non-repetitive Peak Forward Surge Current @t= 8.3ms	2	
$P_D$	Power Dissipation	400	mW
$R_{\theta JA}$	Thermal Resistance from Junction to Ambient	312	°C/W
$T_j$	Junction Temperature	150	°C
$T_{stg}$	Storage Temperature	-55~+150	°C

### Electrical Specification ( $T_A=25^\circ C$ unless otherwise specified)

Parameter	Symbol	Test conditions	Min	Typ	Max	Unit
Reverse voltage	$V_{(BR)}$	$I_R=5\mu A$	75			V
		$I_R=100\mu A$	100			V
Reverse current	$I_R$	$V_R=20V$			25	nA
		$V_R=75V$			5	μA
Forward voltage	$V_F$	$I_F=10mA$			1	V
Total capacitance	$C_{tot}$	$V_R=0V, f=1MHz$			4	pF
Reverse recovery time	$t_{rr}$	$I_F= I_R=30mA, I_{rr}=0.1\times I_R, R_L=100\Omega$			4	ns

### MARKING: 5D

## RATINGS AND CHARACTERISTIC CURVES

